## MICROCHIP PIC12F6XX/PIC16F6XX

### PIC12F6XX/16F6XX Memory Programming Specification

This document includes the programming specifications for the following device:

PIC12F635

• PIC12F683

PIC16F688

PIC16F636

PIC16F684

## 1.0 PROGRAMMING THE PIC12F6XX/16F6XX DEVICES

The PIC12F6XX/16F6XX are programmed using a serial method. The Serial mode will allow the PIC12F6XX/16F6XX to be programmed while in the user's system. This allows for increased design flexibility. This programming specification applies to the PIC12F6XX/16F6XX devices in all packages.

### 1.1 Hardware Requirements

PIC12F6XX/16F6XX devices require one power supply for VDD (5.0V) and one for VPP (12V).

### 1.2 Program/Verify Mode

The Program/Verify mode for the PIC12F6XX/16F6XX devices allow programming of user program memory, data memory, user ID locations, calibration word and the configuration word.

Programming and verification can take place on any memory region, independent of the remaining regions. This allows independent programming of program and data memory regions. Therefore, data memory can be not code-protected, reprogrammed and protected again without loosing the content in the program memory, whether it is code-protected or not.

FIGURE 1-1: 8-PIN, 14-PIN AND 20-PIN DIAGRAMS FOR PIC12F6XX/16F6XX

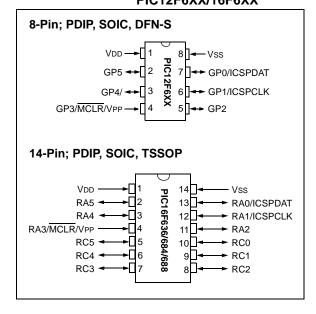


TABLE 1-1: PIN DESCRIPTIONS IN PROGRAM/VERIFY MODE: PIC12F6XX/16F6XX

Pin Name		During Programming							
Pili Name	Function	Pin Type	Pin Description						
GP1/RA1	ICSPCLK	I	Clock input – Schmitt Trigger input						
GP0/RA0	ICSPDAT	I/O	Data input/output – Schmitt Trigger input						
MCLR	Program/Verify mode	P <sup>(1)</sup>	Program Mode Select						
VDD	VDD	Р	Power Supply						
Vss	Vss	Р	Ground						

**Legend:** I = Input, O = Output, P = Power

Note 1: In the PIC12F6XX/16F6XX, the programming high voltage is internally generated. To activate the Program/Verify mode, high voltage needs to be applied to MCLR input. Since the MCLR is used for a level source, MCLR does not draw any significant current.

### 2.0 MEMORY DESCRIPTION

### 2.1 Program Memory Map

The user memory space extends from 0x0000 to 0x1FFF. In Program/Verify mode, the program memory space extends from 0x0000 to 0x3FFF, with the first half (0x0000-0x1FFF) being user program memory and the second half (0x2000-0x3FFF) being configuration memory. The PC will increment from 0x0000 to 0x1FFF and wrap to 0x000, 0x2000 to 0x3FFF and wrap around to 0x2000 (not to 0x0000). Once in configuration memory, the highest bit of the PC stays a '1', thus always pointing to the configuration memory. The only way to point to user program memory is to reset the part and re-enter Program/Verify mode as described in Section 3.0 "Program/Verify Mode".

For the PIC12F683/PIC16F684/PIC16F688 devices, the configuration memory space, 0x2000-0x2008 are physically implemented. However, only locations 0x2000 to 0x2003, 0x2007 and 0x2008 are available. Other locations are reserved.

For the PIC12F635/PIC16F636 devices, the configuration memory space (0x2000-0x2009) are physically implemented. However, only locations 0x2000 to 0x2003 and locations 0x2006 to 0x2009 are available. Other locations are reserved.

#### 2.2 User ID Locations

A user may store identification information (user ID) in four designated locations. The user ID locations are mapped in 0x2000-0x2003. It is recommended that the user use only the seven Least Significant bits (LSb) of each user ID location. The user ID locations read out normally, even after code protection is enabled. It is recommended that ID locations are written as 'xx xxxx xbbb bbbb' where 'bbb bbbb' is user ID information.

The 14 bits may be programmed, but only the 7 LSb's are displayed by MPLAB<sup>®</sup> IDE. The xxxx's are "don't care" bits and are not read by MPLAB<sup>®</sup> IDE.

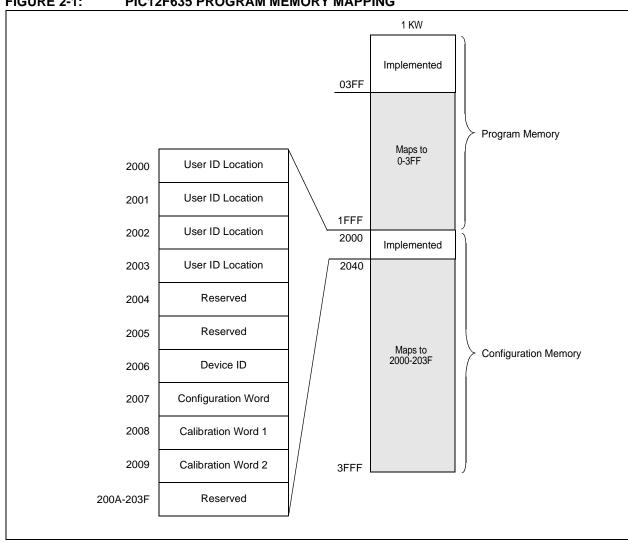
#### 2.3 Calibration Word

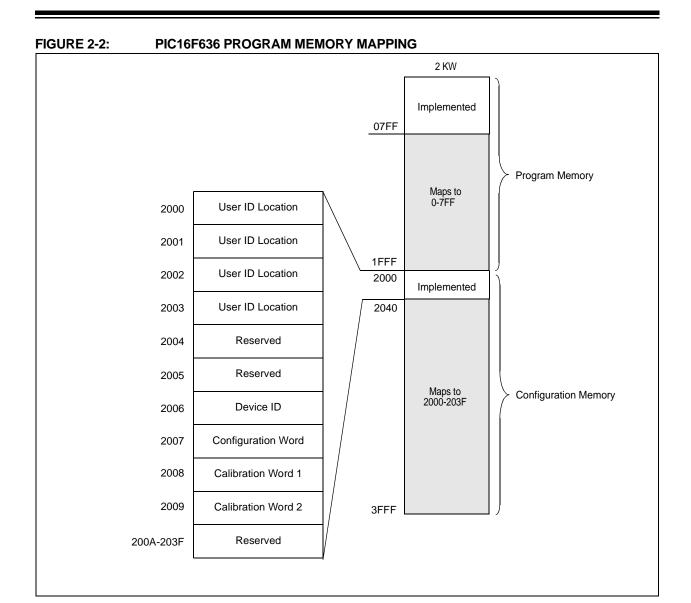
For the PIC12F683/PIC16F684/PIC16F688 devices, the 8 MHz internal oscillator (INTOSC), the Power-on Reset (POR) and the Brown-out Detect (BOD) modules are factory calibrated. These values are stored in the calibration word (0x2008). See the applicable device data sheet for more information.

For the PIC12F635/PIC16F636 devices, the 8 MHz internal oscillator (INTOSC), the Power-on Reset (POR) and the Brown-out Detect (BOD) modules are factory calibrated and stored in the calibration word (0x2008). The Wake-up Reset (WUR) and Low-voltage Detect (LVD) modules are factory calibrated and stored in the calibration word (0x2009). See the applicable device data sheet for more information.

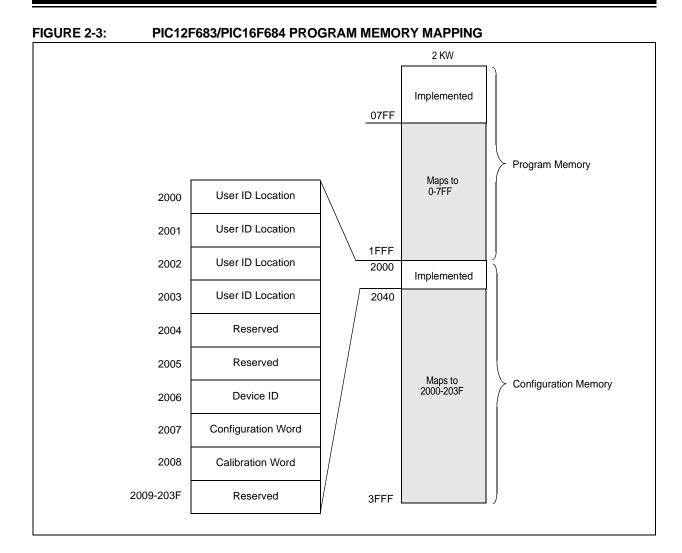
The calibration word does not necessarily participate in the erase operation unless a specific procedure is executed. Therefore, the device can be erased without affecting the calibration word. This simplifies the erase procedure, for these values do not need to be read and restored after the device is erased. See Section 3.1.5.12 "Row Erase Program Memory" for more information on the various erase sequences.

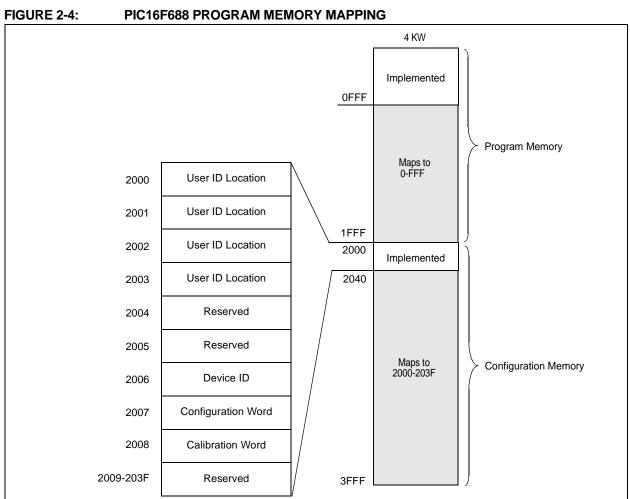
FIGURE 2-1: PIC12F635 PROGRAM MEMORY MAPPING





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### 3.0 PROGRAM/VERIFY MODE

Two methods are available to enter Program/Verify mode. The "VPP-first" is entered by holding ICSPDAT and ICSPCLK low while raising MCLR pin from VIL to VIHH (high voltage), then applying VDD and data. This method can be used for any configuration word selection and **must** be used if the INTOSC and internal MCLR options are selected (FOSC<2:0> = 100 or 101 and MCLRE = 0). The VPP-first entry prevents the device from executing code prior to entering Program/ Verify mode. See the timing diagram in Figure 3-1.

The second entry method, "VDD-first", is entered by applying VDD, holding ICSPDAT and ICSPCLK low, then raising MCLR pin from VIL to VIHH (high voltage), followed by data. This method can be used for any configuration word selection except when INTOSC and internal  $\overline{MCLR}$  options are selected ( $\overline{FOSC} < 2:0 > = 100$  or 101 and  $\overline{MCLRE} = 0$ ). This technique is useful when programming the device when VDD is already applied, for it is not necessary to disconnect VDD to enter Program/Verify mode. See the timing diagram in Figure 3-2.

Once in this mode, the program memory, data memory and configuration memory can be accessed and programmed in serial fashion. ICSPDAT and ICSPCLK are Schmitt Trigger inputs in this mode. RA4 is tri-state, regardless of fuse setting.

The sequence that enters the device into the Programming/Verify mode places all other logic into the Reset state (the MCLR pin was initially at VIL). Therefore, all I/O's are in the Reset state (high-impedance inputs) and the Program Counter (PC) is cleared.

To prevent a device configured with INTOSC and internal MCLR from executing after exiting Program/ Verify mode; VDD needs to power-down before VPP. See Figure 3-3 for the timing.

FIGURE 3-1: VPP-FIRST PROGRAM/ VERIFY MODE ENTRY

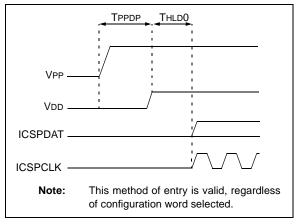


FIGURE 3-2: VDD-FIRST PROGRAM/ VERIFY MODE ENTRY

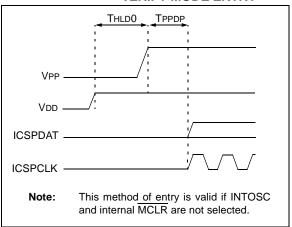
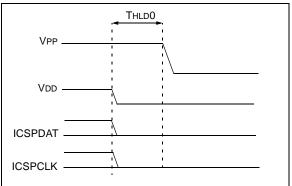


FIGURE 3-3: PROGRAM/VERIFY MODE EXIT



### 3.1 Program/Erase Algorithms

The PIC12F6XX/16F6XX program memory may be written in two ways. The fastest method writes four words at a time. However, one-word writes are also supported for backward compatibility with previous 8-pin and 14-pin Flash devices. The four-word algorithm is used to program the program memory only. The one-word algorithm can write any available memory location (i.e., program memory, configuration memory and data memory).

After writing the array, the PC may be reset and read back to verify the write. It is not possible to verify immediately following the write because the PC can only increment, not decrement.

A device Reset will clear the PC and set the address to '0'. The Increment Address command will increment the PC. The Load Configuration command will set the PC to 0x2000. The available commands are shown in Table 3-1.

#### 3.1.1 FOUR-WORD PROGRAMMING

Only the program memory can be written using this algorithm. Data and configuration memory (>0x2000) must use the One-word Programming Algorithm (Section 3.1.2 "One-Word Programming").

This algorithm writes four sequential addresses in program memory. The four addresses must point to a four-word block with addresses modulo 4 of 0, 1, 2 and 3. For example, programming address 4 though 7 can be programmed together. Programming addresses 2 through 5 will create an unexpected result.

The sequence for programming four words of program memory at a time is as follows:

- Load a word at the current program memory address using Load Data For Program Memory command.
- Issue an Increment Address command.
- Load a word at the current program memory address using Load Data For Program Memory command
- 4. Repeat Step 2 and Step 3 two times.
- Issue a Begin Programming command either internally or externally timed.
- Wait TPROG1 (internally timed) or TPROG2 (externally timed).
- 7. Issue End Programming if externally timed.
- 8. Issue an Increment Address command.
- Repeat this sequence as required to write program memory.

See Figure 3-17 for more information.

#### 3.1.2 ONE-WORD PROGRAMMING

The program memory may also be written one word at a time to allow compatibility with other 8-pin and 14-pin Flash PICmicro<sup>®</sup> devices. Configuration memory (>0x2000) and data memory must be written one word (or byte) at a time.

Note: The four write latches must be reset after programming the device ID (0x2006), Configuration Word (0x2007) or calibration words (0x2008-0x2009). See Section 3.1.3 "Resetting Write Latches".

The sequence for programming one word of program memory at a time is as follows:

- Load a word at the current program memory address using Load Data For Program Memory command
- Issue a Begin Programming command either internally or externally timed.
- Wait TPROG1 (internally timed) or TPROG2 (externally timed).
- 4. Issue End Programming if externally timed.
- 5. Issue an Increment Address command.
- 6. Repeat this sequence as required to write program, data or configuration memory.

See Figure 3-16 for more information.

### 3.1.3 RESETTING WRITE LATCHES

The device ID (0x2006), configuration word (0x2007) and calibration words (0x2008-0x2009) are mapped into the configuration memory, but do not physically reside in it. As a result, the write latches are not reset when programming these locations and must be reset by the programmer. This can be done in two ways, either loading all four latches with '1's or by exiting Program/Verify mode.

The sequence for manually resetting the write latches is as follows:

- Load a word using Load Data For Program Memory or Load Data For Configuration Memory command with a data word of all '1's.
- 2. Issue an Increment Address command.
- Repeat this sequence three times to reset all four write latches.

#### 3.1.4 ERASE ALGORITHMS

The PIC12F6XX/16F6XX will erase different memory locations depending on the Program Counter (PC), CP and CPD values and which erase command executed. The following sequences can be used to erase noted memory locations. In each sequence, the data memory will be erased if the CPD bit in the configuration word is programmed (clear).

To erase the program memory and configuration word (0x2007), the following sequence must be performed. Note the calibration words (0x2008-0x2009) and user ID (0x2000-0x2003) **will not** be erased.

- 1. Do a Bulk Erase Program Memory command.
- 2. Wait TERA to complete erase.

To erase the user ID (0x2000-0x2003), configuration word (0x2007) and program memory, use the following sequence. Note that the calibration words (0x2008-0x2009) **will not** be erased.

- Perform Load Configuration with dummy data to point the Program Counter (PC) to 0x2000.
- Perform a Bulk Erase Program Memory command.
- 3. Wait TERA to complete erase.

To erase the user ID (0x2000-0x2003), configuration word (0x2007), calibration word (0x2008) and program memory, use the following sequence. Note that the calibration word (0x2008) **will** be erased.

- Perform Load Configuration with dummy data to point the Program Counter (PC) to 0x2000.
- Perform 8 Increment Address commands to point the PC to the calibration word at 0x2008.
- 3. Do a Bulk Erase Program Memory command.
- 4. Wait TERA to complete erase.

To erase the user ID (0x2000-0x2003), configuration word (0x2007), calibration words (0x2008-0x2009), and program memory, use the following sequence. Note that the calibration words (0x2008-0x2009) will be erased.

- 1. Perform Load Configuration with dummy data to point the Program Counter (PC) to 0x2000.
- Perform 9 Increment Address commands to point the PC to the calibration word at 0x2009.
- 3. Do a Bulk Erase Program Memory command.
- 4. Wait TERA to complete erase.

To erase the data memory, use the following sequence:

- Perform a Bulk Erase Data Memory command.
- 2. Wait TERA to complete erase.

## 3.1.5 SERIAL PROGRAM/VERIFY OPERATION

The ICSPCLK pin is used as a clock input and the ICSPDAT pin is used for entering command bits and data input/output during serial operation. To input a command, ICSPCLK is cycled six times. Each command bit is latched on the falling edge of the clock with the LSb of the command being input first. The data input onto the ICSPDAT pin is required to have a minimum setup and hold time (see Table 6-1), with respect to the falling edge of the clock. Commands that have data associated with them (Read and Load) are specified to have a minimum delay of 1 µs between the command and the data. After this delay, the clock pin is cycled 16 times with the first cycle being a Start bit and the last cycle being a Stop bit.

During a read operation, the LSb will be transmitted onto ICSPDAT pin on the rising edge of the second cycle. For a load operation, the LSb will be latched on the falling edge of the second cycle. A minimum 1  $\mu$ s delay is also specified between consecutive commands, except for the End Programming command, which requires a 100  $\mu$ s TDIS.

All commands and data words are transmitted LSb first. Data is transmitted on the rising edge and latched on the falling edge of the ICSPCLK. To allow for decoding of commands and reversal of data pin configuration, a time separation of at least 1  $\mu s$  is required between a command and a data word.

The commands that are available are described in Table 3-1.

TABLE 3-1: COMMAND MAPPING FOR PIC12F6XX/16F6XX

Command		Мар	ping (N	Data			
Load Configuration	x	x	0	0	0	0	0, data (14), 0
Load Data for Program Memory	х	x	0	0	1	0	0, data (14), 0
Load Data for Data Memory	х	х	0	0	1	1	0, data (8), zero (6), 0
Read Data from Program Memory	х	х	0	1	0	0	0, data (14), 0
Read Data from Data Memory	х	x	0	1	0	1	0, data (8), zero (6), 0
Increment Address	х	х	0	1	1	0	
Begin Programming	х	0	1	0	0	0	Internally Timed
Begin Programming	х	1	1	0	0	0	Externally Timed
End Programming	х	0	1	0	1	0	
Bulk Erase Program Memory	х	х	1	0	0	1	Internally Timed
Bulk Erase Data Memory	х	х	1	0	1	1	Internally Timed
Row Erase Program Memory	х	1	0	0	0	1	Internally Timed

### 3.1.5.1 LOAD CONFIGURATION

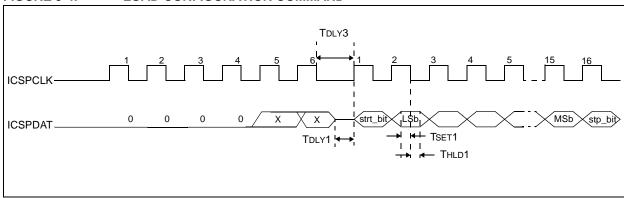
The Load Configuration command is used to access the configuration word (0x2007) user ID (0x2000-0x2003) and calibration words (0x2008-0x2009). This command sets the Program Counter (PC) to address 0x2000 and loads the data latches with one word of data.

To access the configuration memory, send the Load Configuration command. Individual words within the configuration memory can be accessed by sending Increment Address commands and issuing load or read data for program memory.

After the 6-bit command is input, ICSPCLK pin is cycled an additional 16 times for the Start bit, 14 bits of data and a Stop bit (see Figure 3-4).

After the configuration memory is entered, the only way to get back to the program memory is to exit the Program/Verify mode by taking MCLR low (VIL).

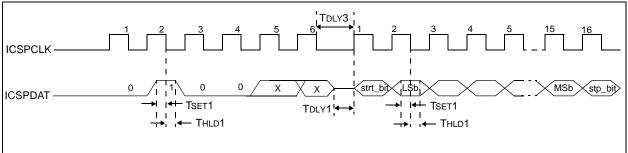
FIGURE 3-4: LOAD CONFIGURATION COMMAND



## 3.1.5.2 LOAD DATA FOR PROGRAM MEMORY

After receiving this command, the chip will load in a 14-bit "data word" when 16 cycles are applied, as described previously. A timing diagram for the Load Data For Program Memory command is shown in Figure 3-5.

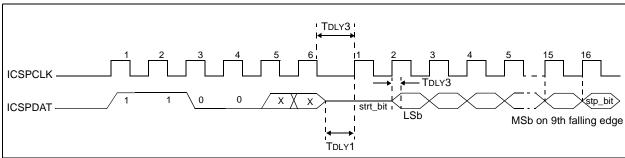
FIGURE 3-5: LOAD DATA FOR PROGRAM MEMORY COMMAND



#### 3.1.5.3 LOAD DATA FOR DATA MEMORY

After receiving this command, the chip will load in a 14-bit "data word" when 16 cycles are applied. However, the data memory is only 8-bits wide and thus, only the first 8 bits of data after the Start bit will be programmed into the data memory. It is still necessary to cycle the clock the full 16 cycles in order to allow the internal circuitry to reset properly. The data memory contains 256 bytes.

FIGURE 3-6: LOAD DATA FOR DATA MEMORY COMMAND

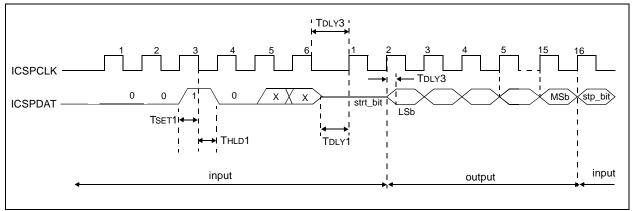


## 3.1.5.4 READ DATA FROM PROGRAM MEMORY

After receiving this command, the chip will transmit data bits out of the program memory (user or configuration) currently accessed, starting with the second rising edge of the clock input. The data pin will go into Output mode on the second rising clock edge, and it will revert to Input mode (high-impedance) after the 16th rising edge.

If the program memory is code-protected ( $\overline{CP} = 0$ ), the data is read as zeros.

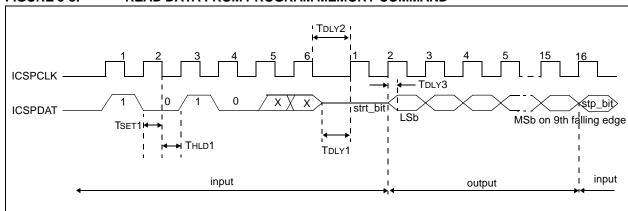
FIGURE 3-7: READ DATA FROM PROGRAM MEMORY COMMAND



## 3.1.5.5 READ DATA FROM PROGRAM MEMORY

After receiving this command, the chip will transmit data bits out of the data memory, starting with the second rising edge of the clock input. The ICSPDAT pin will go into Output mode on the second rising edge and it will revert to Input mode (high-impedance) after the 16th rising edge. As previously stated, the data memory is 8-bits wide, and therefore, only the first 8 bits that are output are actual data. If the data memory is code-protected, the data is read as all zeros. A timing diagram of this command is shown in Figure 3-8.

FIGURE 3-8: READ DATA FROM PROGRAM MEMORY COMMAND

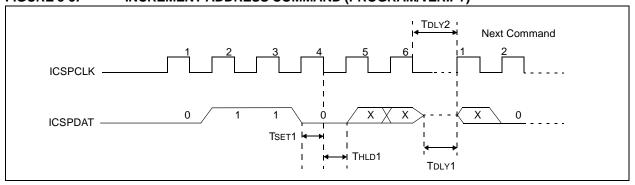


### 3.1.5.6 INCREMENT ADDRESS

The PC is incremented when this command is received. A timing diagram of this command is shown in Figure 3-9.

It is not possible to decrement the address counter. To reset this counter, the user should exit and re-enter Program/Verify mode.

FIGURE 3-9: INCREMENT ADDRESS COMMAND (PROGRAM/VERIFY)

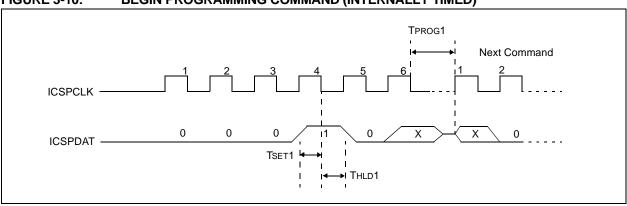


#### 3.1.5.7 **BEGIN PROGRAMMING (Internally** Timed)

A load command must be given before every Begin Programming command. Programming of the appropriate memory (user program memory, configuration memory or data memory) will begin after this command is received and decoded. An internal timing mechanism executes a write. The user must allow for program cycle time for programming to complete. No End Programming command is required.

The addressed location is not erased before programming.

**FIGURE 3-10: BEGIN PROGRAMMING COMMAND (INTERNALLY TIMED)** 

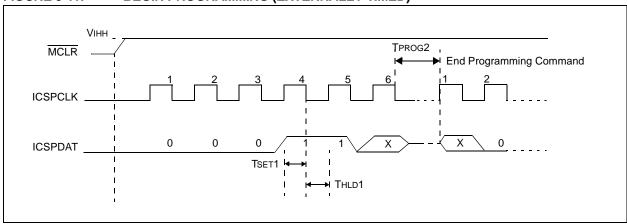


#### 3.1.5.8 **BEGIN PROGRAMMING (Externally** Timed)

A load command must be given before every Begin Programming command. Programming of the appropriate memory (program memory, configuration or data memory) will begin after this command is received and decoded. Programming requires (TPROG2) time and is terminated using an End Programming command.

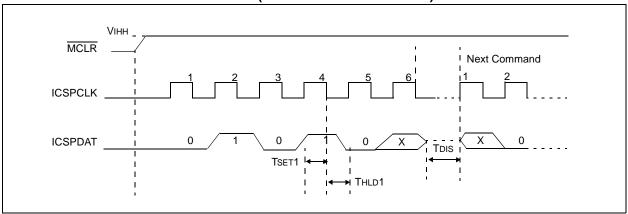
The addressed location is not erased before programming.

**FIGURE 3-11: BEGIN PROGRAMMING (EXTERNALLY TIMED)** 



### 3.1.5.9 END PROGRAMMING

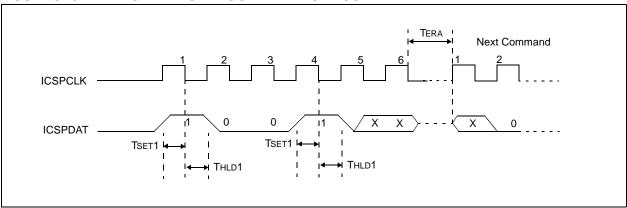
### FIGURE 3-12: END PROGRAMMING (SERIAL PROGRAM/VERIFY)



## 3.1.5.10 BULK ERASE PROGRAM MEMORY

After this command is performed, the entire program memory and configuration word (0x2007) is erased. Data memory will also be erased if the  $\overline{\text{CPD}}$  bit in the configuration word is programmed (clear). See Section 3.1.4 "Erase Algorithms" for erase sequences.

FIGURE 3-13: BULK ERASE PROGRAM MEMORY COMMAND



#### 3.1.5.11 BULK ERASE DATA MEMORY

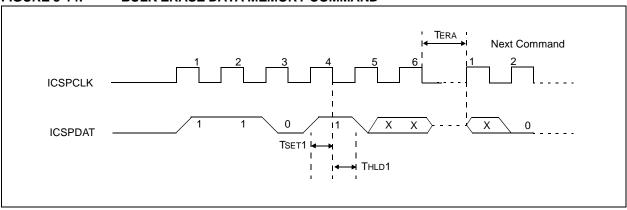
To perform an erase of the data memory, the following sequence must be performed.

- 1. Perform a Bulk Erase Data Memory command.
- 2. Wait TERA to complete bulk erase.

Data memory won't erase if code-protected ( $\overline{CPD} = 0$ ).

Note: All bulk erase operations must take place between 4.5V and 5.5V VDD for PIC12F6XX/16F6XX and 2.0V to 5.5V VDD for PIC12F6XX/16F6XX-ICD.

### FIGURE 3-14: BULK ERASE DATA MEMORY COMMAND



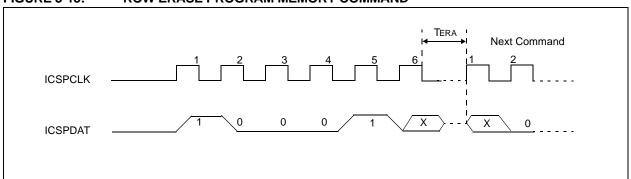
## 3.1.5.12 ROW ERASE PROGRAM MEMORY

This command erases the 16-word row of program memory pointed to by PC<11:4>. If the program memory array is protected  $(\overline{CP}=0)$  or the PC points to configuration memory (>0x2000), the command is ignored.

To perform a Row Erase Program Memory, the following sequence must be performed.

- Execute a Row Erase Program Memory command.
- 2. Wait TERA to complete a row erase.

### FIGURE 3-15: ROW ERASE PROGRAM MEMORY COMMAND



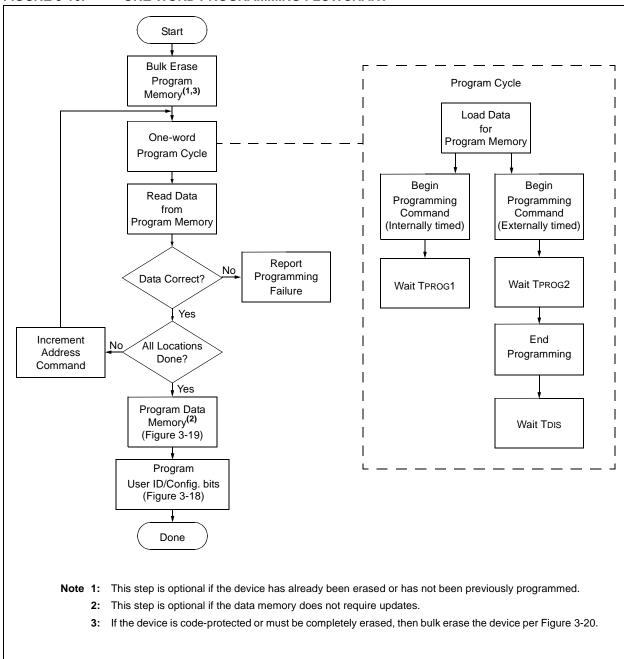
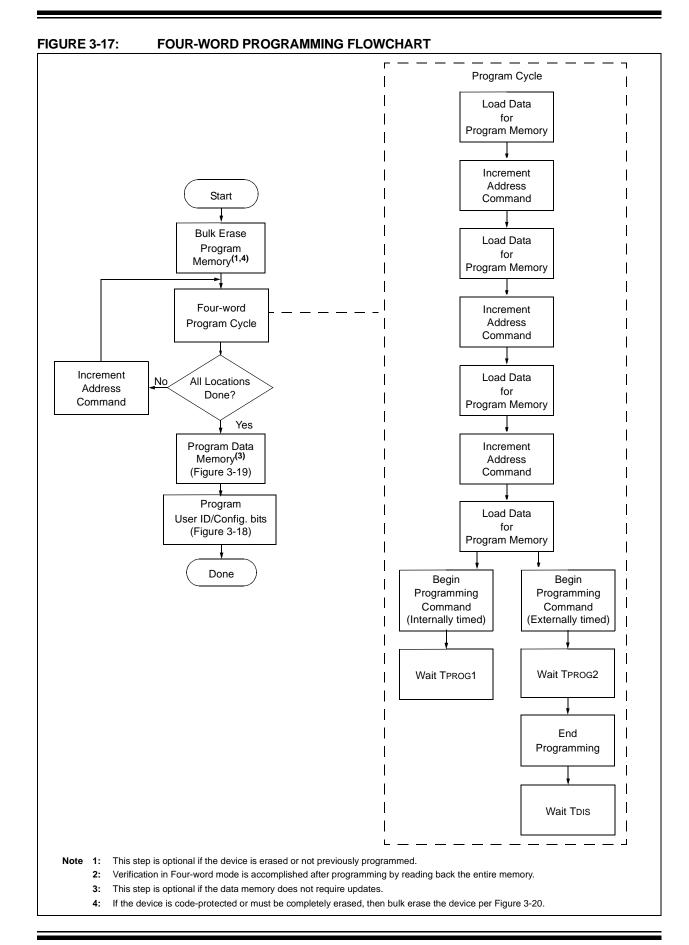
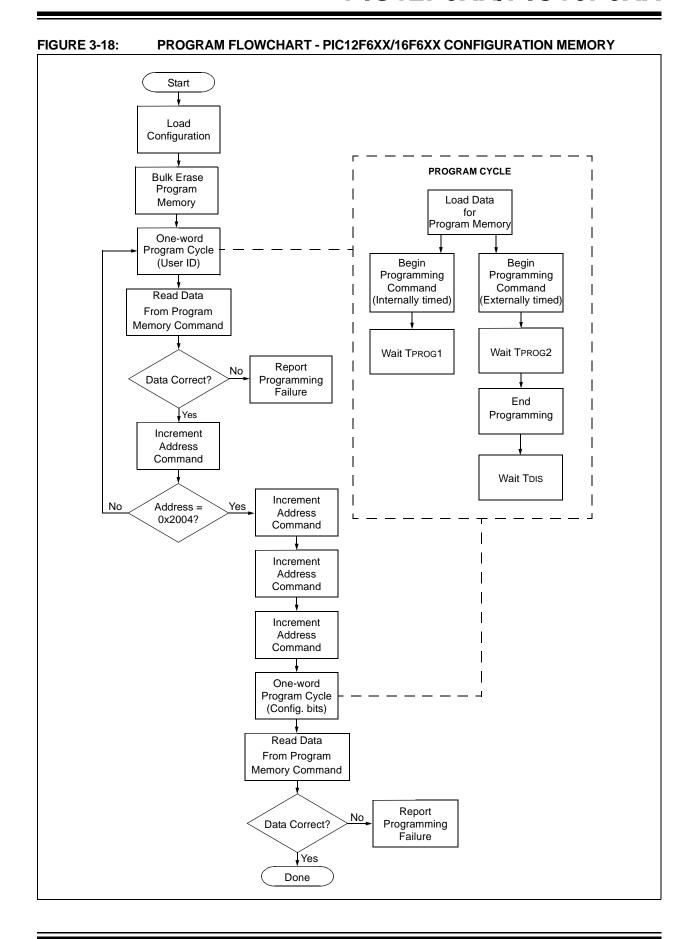


FIGURE 3-16: ONE-WORD PROGRAMMING FLOWCHART





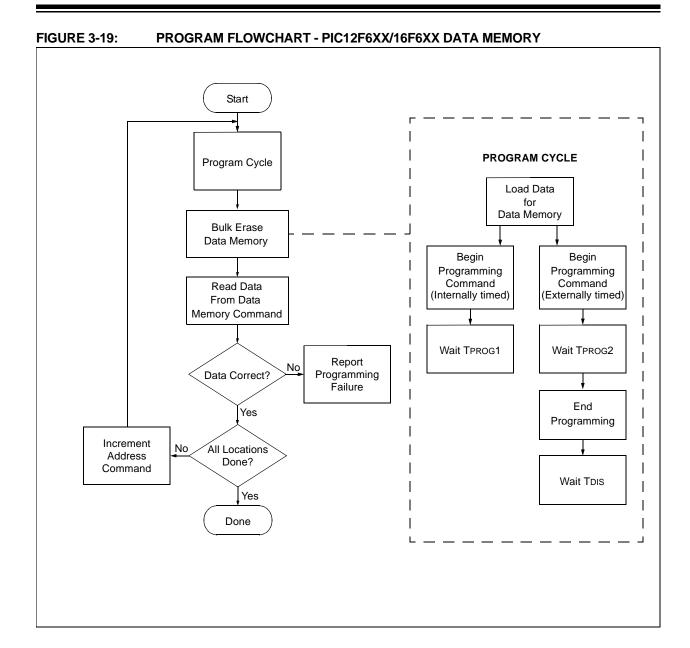
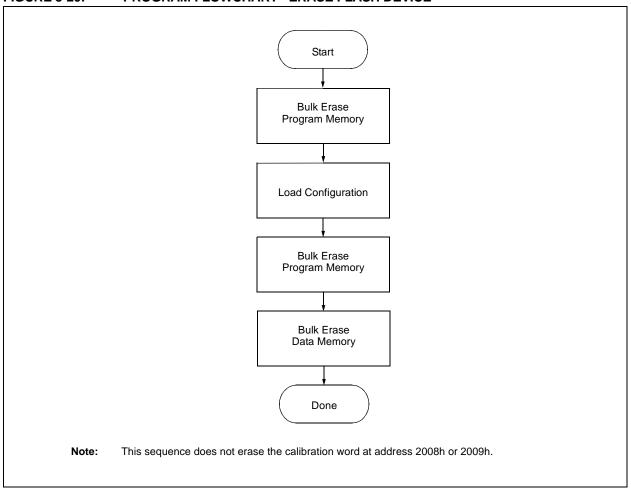


FIGURE 3-20: PROGRAM FLOWCHART - ERASE FLASH DEVICE



### 4.0 CONFIGURATION WORD

The PIC12F6XX/16F6XX has several configuration bits. These bits can be programmed (reads '0') or left unchanged (reads '1'), to select various device configurations.

### REGISTER 4-1: CONFIG - CONFIGURATION WORD (ADDRESS: 2007h) (PIC12F635/PIC16F636)

	U-1	R/P-1	R/P-1	R/P-1	R/P-1	R/P-1	R/P-1	R/P-1	R/P-1	R/P-1	R/P-1	R/P-1	R/P-1	R/P-1
ĺ	_	WURE	FCMEN	IESO	BODEN1	BODEN0	CPD	CP	MCLRE	PWRTE	WDTE	FOSC2	F0SC1	F0SC0
	bit 13													bit 0

bit 13 Unimplemented: Read as '1'

bit 12 WURE: Wake-up Reset Enable bit

1 = Standard wake-up and continue enabled

0 = Wake-up and Reset enabled

bit 11 FCMEN: Fail-Safe Clock Monitor Enable bit

1 = Fail-Safe Clock Monitor enabled

0 = Fail-Safe Clock Monitor disabled

bit 10 IESO: Internal-External Switch Over bit

1 = Internal External Switchover mode enabled

0 = Internal External Switchover mode disabled

bit 9-8 BODEN<1:0>: Brown-out Detect Enable bits

11 = BOD enabled and SBODEN bit disabled

10 = BOD enabled while running and disabled in Sleep. SBODEN bit disabled.

01 = SBODEN in the PCON register controls BOD function

00 = BOD and SBODEN disabled

bit 7 CPD: Data Code Protection bit<sup>(1)</sup>

1 = Data memory is not protected

0 = Data memory is external read-protected

bit 6 **CP**: Code Protection bit<sup>(2)</sup>

1 = Program memory is not code-protected

0 = Program memory is external read and write-protected

bit 5 MCLRE: MCLR Pin Function Select<sup>(4)</sup> bit

 $1 = \overline{MCLR}$  pin is  $\overline{MCLR}$  function and weak internal pull-up is enabled

 $0 = \overline{MCLR}$  pin is alternate function,  $\overline{MCLR}$  function is internally disabled

bit 4 **PWRTE**: Power-up Timer Enable bit<sup>(3)</sup>

1 = PWRT disabled

0 = PWRT enabled

bit 3 WDTE: Watchdog Timer Enable bit

1 = WDT enabled

0 = WDT disabled and can be enabled using SWDTEN in the WDTCON register

bit 2-0 **FOSC<2:0>**: Oscillator Selection bits

000 = LP oscillator: Low-power crystal on RA5/T1CKI/OSC1/CLKIN and RA4/T1G/OSC2/CLKOUT

001 = XT oscillator: Crystal/resonator on RA5/T1CKI/OSC1/CLKIN and RA4/T1G/OSC2/CLKOUT

010 = HS oscillator: High-speed crystal/resonator on RA5/T1CKI/OSC1/CLKIN and RA4/T1G/OSC2/CLKOUT

011 = EC: I/O function on RA4/T1G/OSC2/CLKOUT, CLKIN on RA5/T1CKI/OSC1/CLKIN

100 = INTOSCIO oscillator: I/O function on RA4/T1G/OSC2/CLKOUT, I/O function on RA5/T1CKI/OSC1/CLKIN

101 = INTOSC oscillator: CLKOUT function on RA4/T1G/OSC2/CLKOUT, I/O function on RA5/T1CKI/OSC1/CLKIN

110 = EXTRCIO oscillator: I/O function on RA4/T1G/OSC2/CLKOUT, RC on RA5/T1CKI/OSC1/CLKIN

= EXTRC oscillator: CLKOUT function on RA4/T1G/OSC2/CLKOUT, RC on RA5/T1CKI/OSC1/CLKIN

Note 1: The entire data memory will be erased when the code protection is turned off.

2: The entire program memory will be erased when the code protection is turned off.

3: Enabling Brown-out Detect does not automatically enable Power-up Timer.

4: When MCLR is asserted in INTOSC or RC mode, the internal clock oscillator is disabled.

Legend:

R = Readable bit W = Writable bit U = Unimplemented bit, read as '0'

-n = Value at POR '1' = bit is set '0' = bit is cleared x = bit is unknown

## REGISTER 4-2: CONFIG – CONFIGURATION WORD (ADDRESS:2007h) (PIC12F683/PIC16F684/PIC16F688)

U-1	U-1	R/P-1	R/P-1	R/P-1	R/P-1	R/P-1	R/P-1	R/P-1	R/P-1	R/P-1	R/P-1	R/P-1	R/P-1
_	_	FCMEN	IESO	BODEN1	BODEN0	CPD	СР	MCLRE	PWRTE	WDTE	FOSC2	F0SC1	F0SC0

bit 13 bit 0

bit 13-12 Unimplemented: Read as '1'

bit 11 FCMEN: Fail-Safe Clock Monitor Enable bit

1 = Fail-Safe Clock Monitor enabled

0 = Fail-Safe Clock Monitor disabled

bit 10 IESO: Internal-External Switch Over bit

1 = Internal External Switchover mode enabled

0 = Internal External Switchover mode disabled

bit 9-8 BODEN<1:0>: Brown-out Detect Enable bits

11 = BOD enabled and SBODEN bit disabled

10 = BOD enabled while running and disabled in Sleep. SBODEN bit disabled.

01 = SBODEN in the PCON register controls BOD function

00 = BOD and SBODEN disabled

bit 7 CPD: Code Protection Data

1 = Data memory is not protected

0 = Data memory is external read-protected

bit 6 **CP**: Code Protection

1 = Program memory is not code-protected

0 = Program memory is external read and write-protected

bit 5 MCLRE: MCLR Pin Function Select

 $1 = \overline{MCLR}$  pin is  $\overline{MCLR}$  function and weak internal pull-up is enabled

 $0 = \overline{MCLR}$  pin is alternate function,  $\overline{MCLR}$  function is internally disabled

bit 4 **PWRTE**: Power-up Timer Enable bit<sup>(1)</sup>

1 = PWRT disabled

0 = PWRT enabled

bit 3 WDTE: Watchdog Timer Enable bit

1 = WDT enabled

0 = WDT disabled and can be enabled using SWDTEN in the WDTCON register

bit 2-0 FOSC<2:0>: Oscillator Selection bits

000 = LP oscillator: Low-power crystal on RA5/T1CKI/OSC1/CLKIN and RA4/T1G/OSC2/CLKOUT

001 = XT oscillator: Crystal/resonator on RA5/T1CKI/OSC1/CLKIN and RA4/T1G/OSC2/CLKOUT

010 = HS oscillator: High-speed crystal/resonator on RA5/T1CKI/OSC1/CLKIN and RA4/T1G/OSC2/CLKOUT

011 = EC: I/O function on RA4/T1G/OSC2/CLKOUT, CLKIN on RA5/T1CKI/OSC1/CLKIN

100 = INTOSCIO oscillator: I/O function on RA4/T1G/OSC2/CLKOUT, I/O function on RA5/T1CKI/OSC1/CLKIN

101 = INTOSC oscillator: CLKOUT function on RA4/T1G/OSC2/CLKOUT, I/O function on RA5/T1CKI/OSC1/CLKIN

110 = EXTRCIO oscillator: I/O function on RA4/T1G/OSC2/CLKOUT, RC on RA5/T1CKI/OSC1/CLKIN

111 = EXTRC oscillator: CLKOUT function on RA4/T1G/OSC2/CLKOUT, RC on RA5/T1CKI/OSC1/CLKIN

Note 1: The entire data memory will be erased when the code protection is turned off.

2: The entire program memory will be erased when the code protection is turned off.

3: Enabling Brown-out Detect does not automatically enable Power-up Timer.

4: When MCLR is asserted in INTOSC or RC mode, the internal clock oscillator is disabled.

Legend:

R = Readable bit W = Writable bit U = Unimplemented bit, read as '0'

-n = Value at POR '1' = bit is set '0' = bit is cleared x = bit is unknown

## REGISTER 4-3: CALIB – CALIBRATION WORD (ADDRESS: 2008h) (PIC12F683/PIC16F684/PIC16F688)

U-1	R/P-1	U-1	R/P-1	R/P-1	R/P-1	R/P-1	R/P-1						
_	FCAL6	FCAL5	FCAL4	FCAL3	FCAL2	FCAL1	FCAL0		POR1	POR0	BOD2	BOD1	BOD0

bit 13 bit 0

bit 13 Unimplemented: Read as '0'

bit 12-6 FCAL<6:0>: Internal Oscillator Calibration bits

0111111 = Maximum frequency

.

0000001

0000000 = Center frequency

1111111

•

bit 5

1000000 = Minimum frequency

Unimplemented: Read as '0'

bit 4-3 POR<1:0>: POR Calibration bits

00 = Lowest POR voltage11 = Highest POR voltage

bit 2-0 BOD<2:0>: BOD Calibration bits

000 = Reserved

001 = Lowest BOD voltage

111 = Highest BOD voltage

Note 1: This location does not participate in bulk erase operations if the procedure in Figure 3-20 is used.

2: Calibration bits are reserved for factory calibration. These values can and will change across the entire range, therefore, specific values and available adjustment range can not be specified.

Legend:

R = Readable bit W = Writable bit U = Unimplemented bit, read as '0'

-n = Value at POR '1' = bit is set '0' = bit is cleared x = bit is unknown

#### CALIB - CALIBRATION WORD 1 (ADDRESS: 2008h) (PIC12F635/PIC16F636) **REGISTER 4-4:**

_	FCAL6	FCAL5	FCAL4	FCAL3	FCAL2	FCAL1	FCAL0	POR2	POR1	POR0	BOD2	BOD1	BOD0
U-1	R/P-1												

bit 0 bit 13

bit 13 Unimplemented: Read as '0'

bit 12-6 FCAL<6:0>: Internal Oscillator Calibration bits

0111111 = Maximum frequency

0000001

0000000 = Center frequency. Oscillator is running at the calibrated frequency

1111111

1000000 = Minimum frequency

POR<2:0>: POR Calibration bits bit 4-3

111 = Maximum POR voltage

110 101

100 = Center POR voltage

000 = Center POR voltage

001

010

011 = Minimum POR voltage

bit 2-0 BOD<2:0>: BOD Calibration bits

111 = Maximum BOD voltage

110

101

100 = Center BOD voltage

000 = Center BOD voltage

001

010

011 = Minimum BOD voltage

**Note 1:** This location does not participate in bulk erase operation, unless PC = 2008h.

Legend:

R = Readable bit W = Writable bit U = Unimplemented bit, read as '0'

-n = Value at POR '1' = bit is set '0' = bit is cleared x = bit is unknown

### REGISTER 4-5: CALIB – CALIBRATION WORD 2 (ADDRESS: 2009h) (PIC12F635/PIC16F636)

U-1	R/P-1	R/P-1	R/P-1	R/P-1	R/P-1								
_	_				_	_	_	WUR2	WUR1	WUR0	LVD2	LVD1	LVD0

bit 13 bit 0

bit 13-6 Unimplemented: Read as '0'

bit 5-3 **WUR<2:0>:** WUR Calibration bits 111 = Maximum WUR voltage

110

101

100 = Center WUR voltage

000 = Center WUR voltage

001 010

011 = Minimum WUR voltage

bit 2-0 **LVD<2:0>:** LVD Calibration bits

111 = Maximum LVD voltage

110

101

100 = Center LVD voltage

000 = Center LVD voltage

001

010

011 = Minimum LVD voltage

**Note 1:** This location does not participate in bulk erase operation, unless PC = 2009h.

Legend:			
R = Readable bit	W = Writable bit	U = Unimplemented bit, r	ead as '0'
-n = Value at POR	'1' = bit is set	'0' = bit is cleared	x = bit is unknown

### 4.1 Device ID Word

The device ID word for the PIC12F6XX/16F6XX is located at 2006h. This location can not be erased.

TABLE 4-1: DEVICE ID VALUES

Device	Device ID Values							
Device	Dev	Rev						
PIC12F635	00 1111 101	x xxxx						
PIC16F636	01 0000 101	x xxxx						
PIC12F683	01 0010 100	x xxxx						
PIC16F684	01 0000 100	x xxxx						
PIC16F688	01 0001 100	x xxxx						

### 5.0 CODE PROTECTION

For PIC12F6XX/16F6XX, once the  $\overline{\text{CP}}$  bit is programmed to '0', all program memory locations read all '0's. The user ID locations and the configuration word read out in an unprotected fashion. Further programming is disabled for the entire program memory.

Data memory is protected with its own code-protect bit (CPD). When enabled, the data memory can still be programmed and read using the EECON1 register (see the applicable data sheet for more information).

The user ID locations and the configuration word can be programmed regardless of the state of the  $\overline{\text{CP}}$  and  $\overline{\text{CPD}}$  bits.

### 5.1 Disabling Code Protection

It is recommended to use the procedure in Figure 3-20 to disable code protection of the device. This sequence will erase the program memory, data memory, configuration word (0x2007) and user ID locations (0x2000-0x2003). The calibration words (0x2008-0x2009) will **not** be erased.

Note:

To ensure system security, if  $\overline{CPD}$  bit = 0, Bulk Erase Program Memory command will also erase data memory.

# 5.2 Embedding Configuration Word and User ID Information in the Hex File

To allow portability of code, the programmer is required to read the configuration word and user ID locations from the hex file when loading the hex file. If configuration word information was not present in the hex file, a simple warning message may be issued. Similarly, while saving a hex file, configuration word and user ID information must be included. An option to not include this information may be provided.

Specifically for the PIC12F6XX/16F6XX, the data memory should also be embedded in the hex file (see Section 5.3.2 "Embedding Data Memory Contents in HEX File").

Microchip Technology Incorporated feels strongly that this feature is important for the benefit of the end customer.

### 5.3 Checksum Computation

### 5.3.1 CHECKSUM

Checksum is calculated by reading the contents of the PIC12F6XX/16F6XX memory locations and adding up the op codes up to the maximum user addressable location (e.g., 0x7FFF for the PIC16F684). Any carry bits exceeding 16 bits are neglected. Finally, the configuration word (appropriately masked) is added to the checksum. Checksum computation for the PIC12F6XX/16F6XX devices is shown in Table 5-1.

The checksum is calculated by summing the following:

- · The contents of all program memory locations
- The configuration word, appropriately masked
- Masked user ID locations (when applicable)

The Least Significant 16 bits of this sum is the checksum.

The following table describes how to calculate the checksum for each device. Note that the checksum calculation differs depending on the code-protect setting. Since the program memory locations read out zeroes when code-protected, the table describes how to manipulate the actual program memory values to simulate values that would be read from a protected device. When calculating a checksum by reading a device, the entire program memory can simply be read and summed. The configuration word and user ID locations can always be read regardless of code-protect setting.

Note:

Some older devices have an additional value added in the checksum. This is to maintain compatibility with older device programmer checksums.

TABLE 5-1: CHECKSUM COMPUTATIONS

Device	Code Protect	Checksum*	Blank Value	0x25E6 at 0 and Max Address
PIC12F635	OFF	SUM[0x0000:0x03FF] + (CFGW & 1FFF)	0x1BFF	0xE7CD
	ALL	(CFGW and 0x1FFF) + SUM_ID	0x3BBE	0x078C
PIC16F636	OFF	SUM[0x0000:0x07FF] + (CFGW & 1FFF)	0x17FF	0xE3CD
	ON	(CFGW and 0x1FFF) + SUM_ID	0x37BE	0x038C
PIC12F683	OFF	SUM[0x0000:0x07FF] + (CFGW & 0FFF)	0x07FF	0xD3CD
	ON	(CFGW and 0x0FFF) + SUM_ID	0x17BE	0xE38C
PIC16F684	OFF	SUM[0x0000:0x07FF] + (CFGW & 0FFF)	0x07FF	0xD3CD
	ON	(CFGW and 0x0FFF) + SUM_ID	0x17BE	0xE38C
PIC16F688	OFF	SUM[0x0000:0x0FFF] + (CFGW & 0FFF)	0x0FFF	0xD3CD
	ON	(CFGW and 0x0FFF) + SUM_ID	0x17BE	0xE38C

**Legend:** CFGW = Configuration Word. Example calculations assume configuration word is erased (all '1's). SUM[a:b] = [Sum of locations a to b inclusive]

SUM\_ID = User ID locations masked by 0xF then made into a 16-bit value with ID0 as the Most Significant nibble.

For example, ID0 = 0x1, ID1 = 0x2, ID3 = 0x3, ID4 = 0x4, then  $SUM_ID = 0x1234$ .

The 4 LSb's of the unprotected checksum is used for the example calculations.

\*Checksum = [Sum of all the individual expressions] MODULO [0xFFFF]

+ = Addition

& = Bitwise AND

## 5.3.2 EMBEDDING DATA MEMORY CONTENTS IN HEX FILE

The programmer should be able to read data memory information from a hex file and conversely (as an option), write data memory contents to a hex file along with program memory information and configuration word (0x2007) and user ID (0x2000-0x2003) information.

The 256 data memory locations are logically mapped starting at address 0x2100. The format for data memory storage is one data byte per address location, LSb aligned.

### 6.0 PROGRAM/VERIFY MODE ELECTRICAL CHARACTERISTICS

TABLE 6-1: AC/DC CHARACTERISTICS TIMING REQUIREMENTS FOR PROGRAM/VERIFY MODE

AC/DC	CHARACTERISTICS	Standard Operating Operating	Temperat	ure -40°	C ≤ TA ≤ / ≤ VDD ≤	5.5V
Sym	Characteristics	Min	Тур	Max	Units	Conditions/Comments
General						
VDD	VDD level for read/write operations, program and data memory	2.0	_	5.5	V	
VDD	VDD level for bulk erase operations, program and data memory	2.0 4.5	_	5.5 5.5	V V	PIC12F6XX/16F6XX-ICD PIC12F6XX/16F6XX
Vінн	High voltage on MCLR for Program/Verify mode entry	10	_	12	V	
TVHHR	MCLR rise time (Vss to Vhh) for Program/Verify mode entry	_	_	1.0	μs	
TPPDP	Hold time after VPP changes	5	_	_	μs	
VIH1	(ICSPCLK, ICSPDAT) input high level	0.8 VDD	_	_	V	
VIL1	(ICSPCLK, ICSPDAT) input low level	0.2 VDD	_		V	
ТѕЕТО	ICSPCLK, ICSPDAT setup time before MCLR↑ (Program/Verify mode selection pattern setup time)	100	_	_	ns	
THLD0	Hold time after VDD changes	5	_	_	μs	
Serial Pi	ogram/Verify					
TSET1	Data in setup time before clock↓	100	_		ns	
THLD1	Data in hold time after clock↓	100			ns	
TDLY1	Data input not driven to next clock input (delay required between command/data or command/ command)	1.0	_		μs	
TDLY2	Delay between clock↓ to clock↑ of next command or data	1.0	_	_	μs	
TDLY3	Clock↑ to data out valid (during a Read Data command)		_	80	ns	
TERA	Erase cycle time	_	5	6	ms	
TPROG1	Programming cycle time (internally timed)	2 5	_	2.5 6	ms	Program memory Data memory
TPROG2	Programming cycle time (externally timed)	2		2.5	ms	10°C ≤ TA ≤ +40°C Program memory
TDIS	Time delay from program to compare (HV discharge time)	100	_		μs	

NOTES:

#### Note the following details of the code protection feature on Microchip devices:

- Microchip products meet the specification contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is one of the most secure families of its kind on the market today, when used in the
  intended manner and under normal conditions.
- There are dishonest and possibly illegal methods used to breach the code protection feature. All of these methods, to our knowledge, require using the Microchip products in a manner outside the operating specifications contained in Microchip's Data Sheets. Most likely, the person doing so is engaged in theft of intellectual property.
- Microchip is willing to work with the customer who is concerned about the integrity of their code.
- Neither Microchip nor any other semiconductor manufacturer can guarantee the security of their code. Code protection does not mean that we are guaranteeing the product as "unbreakable."

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Tel: 905-673-0699 Fax: 905-673-6509

### ASIA/PACIFIC

Australia

Suite 22, 41 Rawson Street Epping 2121, NSW Australia Tel: 61-2-9868-6733

Tel: 61-2-9868-6733 Fax: 61-2-9868-6755 China - Beijing

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China - Chengdu

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Shenzhen 518033, China Tel: 86-755-82901380 Fax: 86-755-8295-1393

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India

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**Singapore** 200 Middle Road #07-02 Prime Centre Singapore, 188980

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Taiwan

Kaohsiung Branch 30F - 1 No. 8 Min Chuan 2nd Road Kaohsiung 806, Taiwan Tel: 886-7-536-4818 Fax: 886-7-536-4803

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Italy

Via Quasimodo, 12 20025 Legnano (MI) Milan, Italy Tel: 39-0331-742611 Fax: 39-0331-466781

Netherlands

Waegenburghtplein 4 NL-5152 JR, Drunen, Netherlands Tel: 31-416-690399

Fax: 31-416-690340 United Kingdom

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Tel: 44-118-921-5869 Fax: 44-118-921-5820

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